NSN 5961-01-110-8927

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-110-8927 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.145 inches and 0.165 inches **Overall Diameter:** Between 0.065 inches and 0.075 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 breakdown voltage, collector-to-base, emitter open **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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